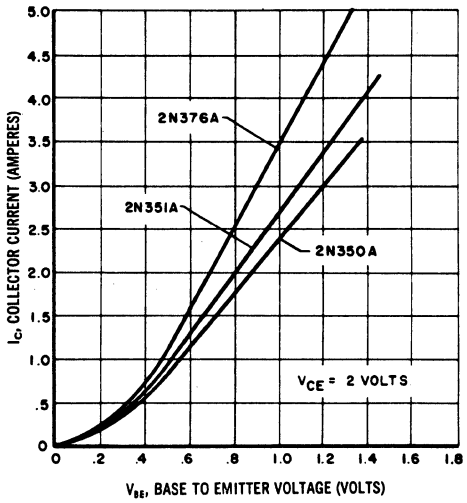
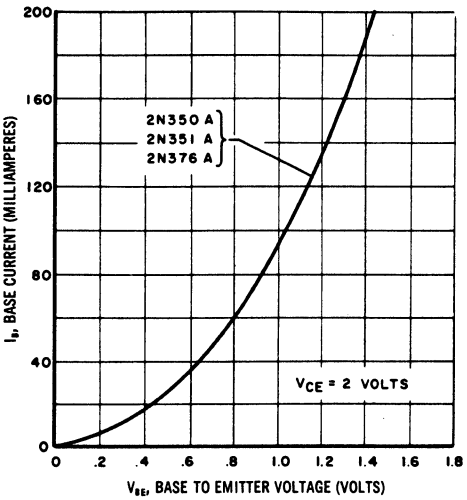
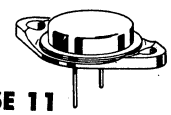
OUTPUT CURRENT versus EMITTER-DRIVE VOLTAGE



INPUT CURRENT versus EMITTER-DRIVE VOLTAGE



2N375 (GERMANIUM)
2N618
2N1359
2N1360
2N1362 thru 2N1365



CASE 11
(TO-3)

PNP germanium power transistors for general purpose switching and amplifier applications.

MAXIMUM RATINGS

Rating	Symbol	2N1359 2N1360	2N375 2N618	2N1362 2N1363	2N1364 2N1365	Unit
Collector-Emitter Voltage	V_{CES}	40	60	75	100	Vdc
Collector-Base Voltage	V_{CB}	50	80	100	120	Vdc
Emitter-Base Voltage	V_{EB}	25	40	50	60	Vdc
Collector Current-Continuous Peak	I_C	3.0 10				Adc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	106 1.25				Watts W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +110				°C

THERMAL CHARACTERISTICS

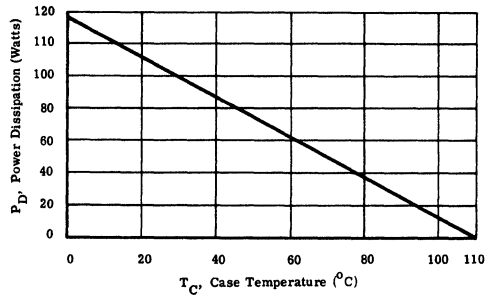
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	0.8	°C/W

2N375, 2N618, 2N1359, 2N1360, 2N1362 thru 2N1365 (continued)

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Types	Symbol	Minimum	Typical	Maximum	Unit
Collector-Base Cutoff Current	2N1359, 2N1360	I_{CBO}				mA
(V_{CB} = 40 V, I_E = 0)			--	--	3.0	
(V_{CB} = 50 V, I_E = 0)			--	--	20.0	
(V_{CB} = 60 V, I_E = 0)	2N375, 2N618		--	--	3.0	
(V_{CB} = 80 V, I_E = 0)			--	--	20.0	
(V_{CB} = 75 V, I_E = 0)	2N1362, 2N1363		--	--	3.0	
(V_{CB} = 100 V, I_E = 0)			--	--	20.0	
(V_{CB} = 100 V, I_E = 0)	2N1364, 2N1365		--	--	3.0	
(V_{CB} = 120 V, I_E = 0)			--	--	20.0	
Collector-Base Cutoff Current at Tc = +90°C V_{CB} = 1/2 BV_{CES} rating		I_{CBO}	--	--	20	mA
Emitter-Base Cutoff Current (V_{EB} = 12 V, I_C = 0)		I_{EBO}	--	--	0.5	mA
(V_{EB} = 25 V, I_C = 0)	2N1359, 2N1360		--	--	20	
(V_{EB} = 50 V, I_C = 0)	2N1362, 2N1363		--	--	20	
(V_{EB} = 60 V, I_C = 0)	2N1364, 2N1365		--	--	20	
Collector-Emitter Breakdown Voltage						Vdc
I_C = 500 mA, V_{EB} = 0)	2N1359, 2N1360	BV_{CES}	40	--	--	
	2N375, 2N618		60	--	--	
	2N1362, 2N1363		75	--	--	
	2N1364, 2N1365		100	--	--	
DC Current Transfer Ratio		h_{FE}				--
(V_{CE} = 4 V, I_C = 1.0A)	2N1359, 375, 1362, 64		35	55	90	
	2N1360, 618, 1363, 65		60	90	140	
(V_{CE} = 4 V, I_C = 1.0A)	2N1359, 375, 1362, 64		15	22	--	
	2N1360, 618, 1363, 65		20	35	--	
Transconductance						mhos
(V_{CE} = 4 V, I_C = 1.0A)	2N375	g_{FE}	0.8	1.25	2.2	
	2N618		1.0	1.6	2.5	
	2N1359, 2N1362, 2N1364		0.8	1.25	--	
	2N1360, 2N1363, 2N1365		1.0	1.6	--	
Frequency Cutoff		$f_{\alpha e}$				kHz
(V_{CE} = 4 V, I_C = 1 A)	2N375		5.0	8.5	--	
(V_{CE} = 4 V, I_C = 1 A)	2N618		5.0	8.5	--	
(V_{CE} = 4 V, I_C = 3 A)	2N1359, 2N1362, 2N1364		7.0	10	--	
(V_{CE} = 4 V, I_C = 3 A)	2N1360, 2N1363, 2N1365		5.0	8.5	--	
Collector Saturation Voltage		$V_{CE(sat)}$				Vdc
(I_C = 2.0 A, I_B = 200mA)	2N1359, 375, 1362, 64		--	0.4	1.0	
	2N1360, 618, 1363, 65		--	0.3	0.8	
Base-Emitter Drive Voltage		V_{BE}				Vdc
(I_C = 2.0A, I_B = 200 mA)	2N1359, 375, 1362, 64		--	0.7	--	
	2N1360, 618, 1363, 65		--	0.6	--	
Collector-Emitter Punch-Through Voltage		V_{EBF}				Vdc
(V_{CB} = 50 V, I_C = 0)	2N1359, 2N1360		--	--	1.25	
(V_{CB} = 100 V, I_C = 0)	2N1362, 2N1363		--	--	1.25	
(V_{CB} = 120 V, I_C = 0)	2N1364, 2N1365		--	--	1.25	

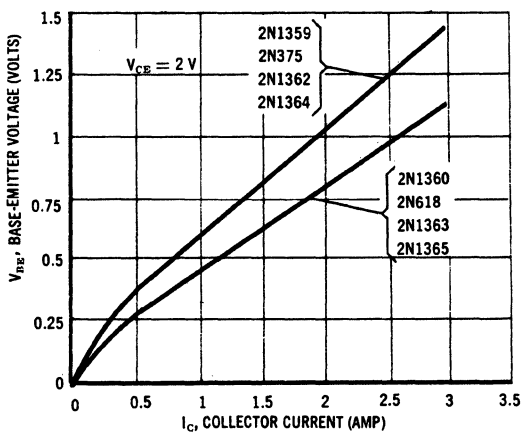
POWER-TEMPERATURE DERATING CURVE



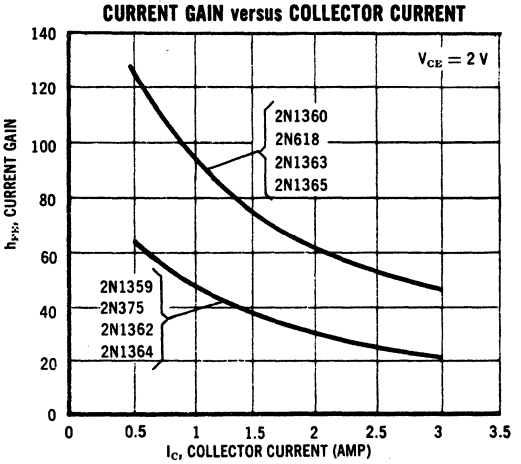
The maximum continuous power is related to maximum junction temperature, by the thermal resistance factor. For d.c. or frequencies below 25 cps the transistor must be operated within the constant $P_D = Vc \times Ic$ hyperbolic curve. This curve has a value of 106 Watts at case temperatures of 25°C and is 0 Watts at 110°C with a linear relation between the two temperatures such that

$$P_D \text{ allowable} = \frac{110^\circ - Tc}{0.8}$$

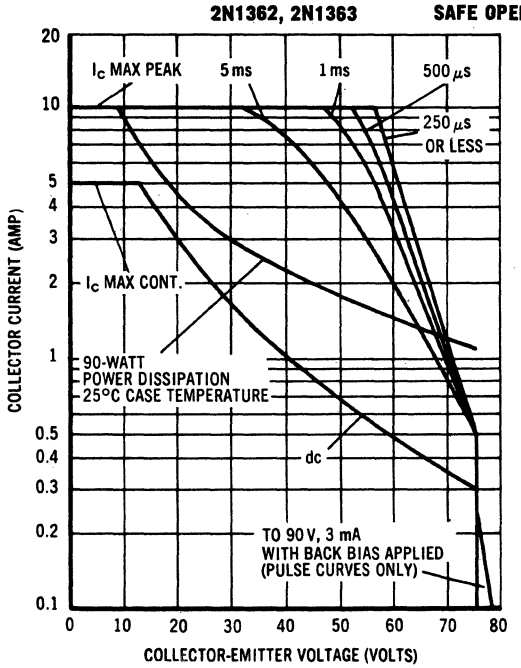
BASE-EMITTER VOLTAGE versus COLLECTOR CURRENT

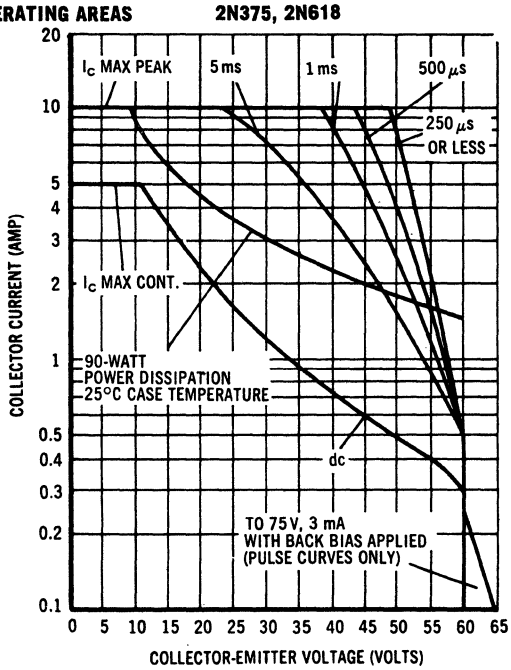


CURRENT GAIN versus COLLECTOR CURRENT



2N1362, 2N1363 SAFE OPERATING AREAS 2N375, 2N618





The Safe Operating Area Curves indicate I_C — V_{CE} limits below which the device will not go into secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a collector-emitter short. (Duty cycle of the excursions make no significant change in these safe areas.) To insure operation below the maximum T_J, the power-temperature derating curve must be observed for both steady state and pulse power conditions.